

2021 Virtual School on Electron-Phonon Physics and the EPW code

June 14-18 2021



Lecture Tue.1

Introduction to electron-phonon interactions

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Lecture Summary

- Heuristic approach to the electron-phonon interaction
- Examples of electron-phonon interactions
- Rayleigh-Schrödinger perturbation theory
- The electron-phonon matrix element
- Wannier interpolation

Ionic degrees of freedom in the Kohn-Sham equations

Where do electron-phonon interactions come from?

Ionic degrees of freedom in the Kohn-Sham equations

$$-\frac{\hbar^2}{2m_e} \nabla^2 \psi_n + V_{\text{SCF}} \psi_n = E_n \psi_n$$

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$$V_{\text{SCF}}(\mathbf{r}) = -\frac{e^2}{4\pi\epsilon_0} \left[\sum_{\kappa} \frac{Z_{\kappa}}{|\mathbf{r} - \boldsymbol{\tau}_{\kappa}|} - \int \frac{n(\mathbf{r}') d\mathbf{r}'}{|\mathbf{r} - \mathbf{r}'|} \right] + V_{xc}[n(\mathbf{r})]$$

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Ionic degrees of freedom in the Kohn-Sham equations

$$\begin{aligned} -\frac{\hbar^2}{2m_e} \nabla^2 \psi_n + V_{\text{SCF}} \psi_n &= E_n \psi_n \\ n(\mathbf{r}) &= \sum_{n \in \text{occ}} |\psi_n(\mathbf{r})|^2 \\ V_{\text{SCF}}(\mathbf{r}) &= -\frac{e^2}{4\pi\epsilon_0} \left[\sum_{\kappa} \frac{Z_{\kappa}}{|\mathbf{r} - \boldsymbol{\tau}_{\kappa}|} - \int \frac{n(\mathbf{r}') d\mathbf{r}'}{|\mathbf{r} - \mathbf{r}'|} \right] + V_{xc}[n(\mathbf{r})] \end{aligned}$$

Atom κ at position $\boldsymbol{\tau}_{\kappa}$

Heuristic approach to electron-phonon interactions

The SCF potential depends **parametrically** on the atomic coordinates

$$V_{\text{SCF}} = V_{\text{SCF}}(\mathbf{r}; \boldsymbol{\tau}_1, \boldsymbol{\tau}_2, \dots)$$

Heuristic approach to electron-phonon interactions

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- Consider only one atom and one Cartesian direction
- Displace atom from equilibrium site, $\tau = \tau_0 + u$

Heuristic approach to electron-phonon interactions

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$$V_{\text{SCF}}(\mathbf{r}; \tau) = V_{\text{SCF}}(\mathbf{r}; \tau_0) + \frac{\partial V_{\text{SCF}}}{\partial \tau} u + \frac{1}{2} \frac{\partial^2 V_{\text{SCF}}}{\partial \tau^2} u^2 + \dots$$

Heuristic approach to electron-phonon interactions

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Perturbation Hamiltonian leading to EPIs

Manifestations of electron-phonon interactions

Electron mobility in monolayer MoS₂

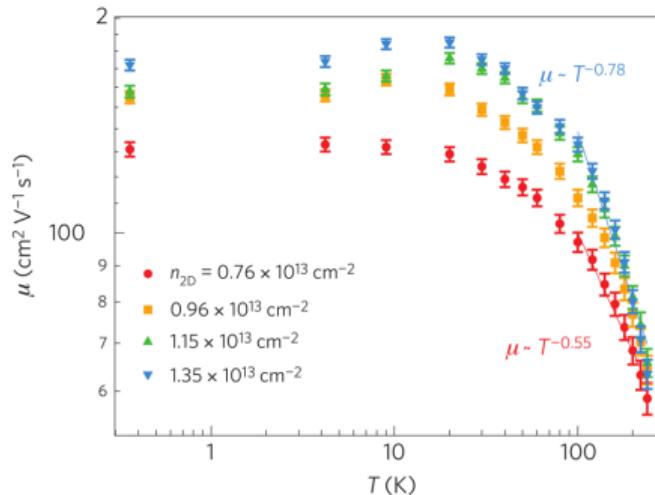
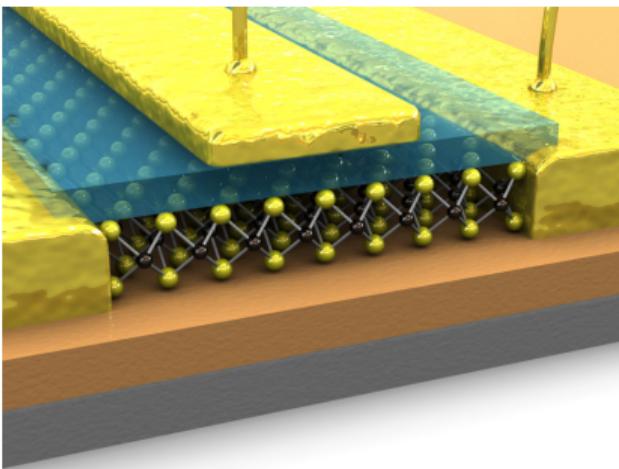
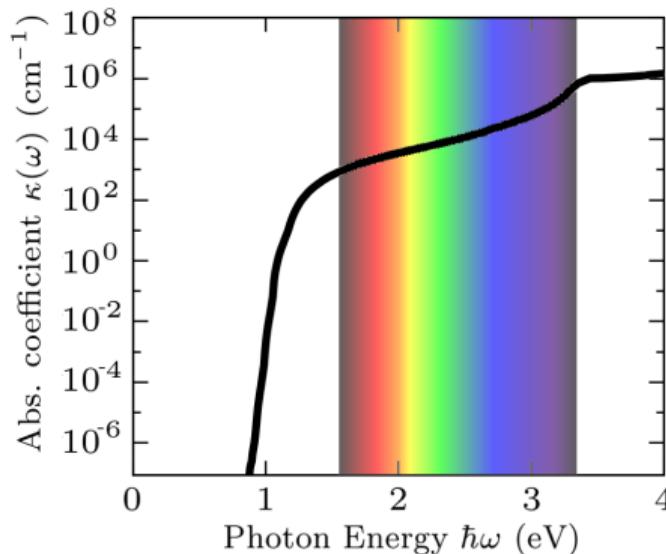


Figure from Radisavljevic and Kis, Nature Mater. 12, 815 (2013)

Manifestations of electron-phonon interactions

Phonon-assisted optical absorption in silicon



Data from Green et al, Prog. Photovolt. Res. Appl. 3, 189 (1995)

Manifestations of electron-phonon interactions

High-temperature superconductivity in compressed H_3S

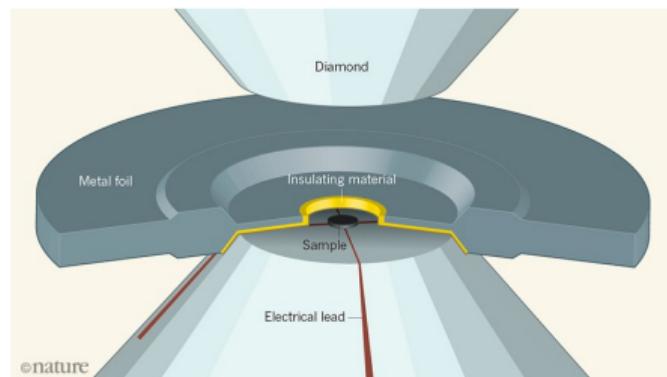
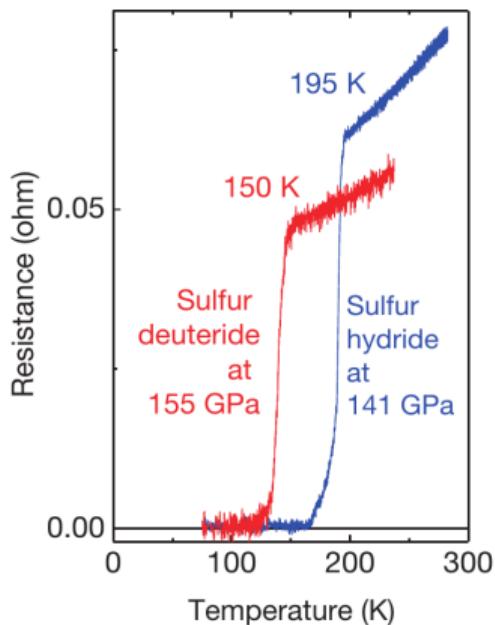


Figure from Drozdov et al, Nature 73, 525 (2015)

Manifestations of electron-phonon interactions

Temperature-dependent photoluminescence in hybrid perovskites

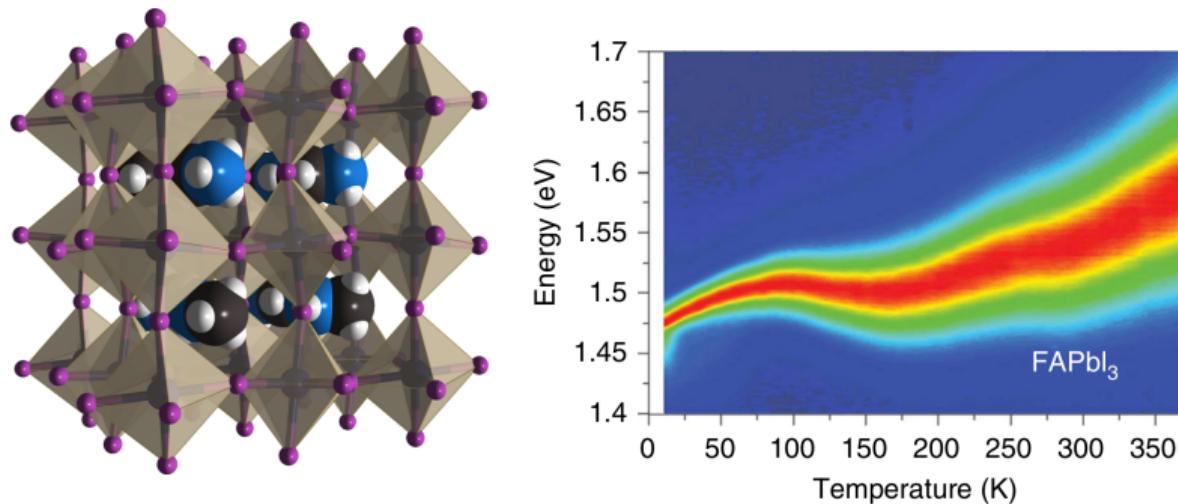


Figure from Wright et al, Nat. Commun. 7, 11755 (2016)

Perturbation Hamiltonian leading to EPIs

$$V_{\text{SCF}}(\mathbf{r}; \tau_0)$$



Perturbation Hamiltonian leading to EPIs

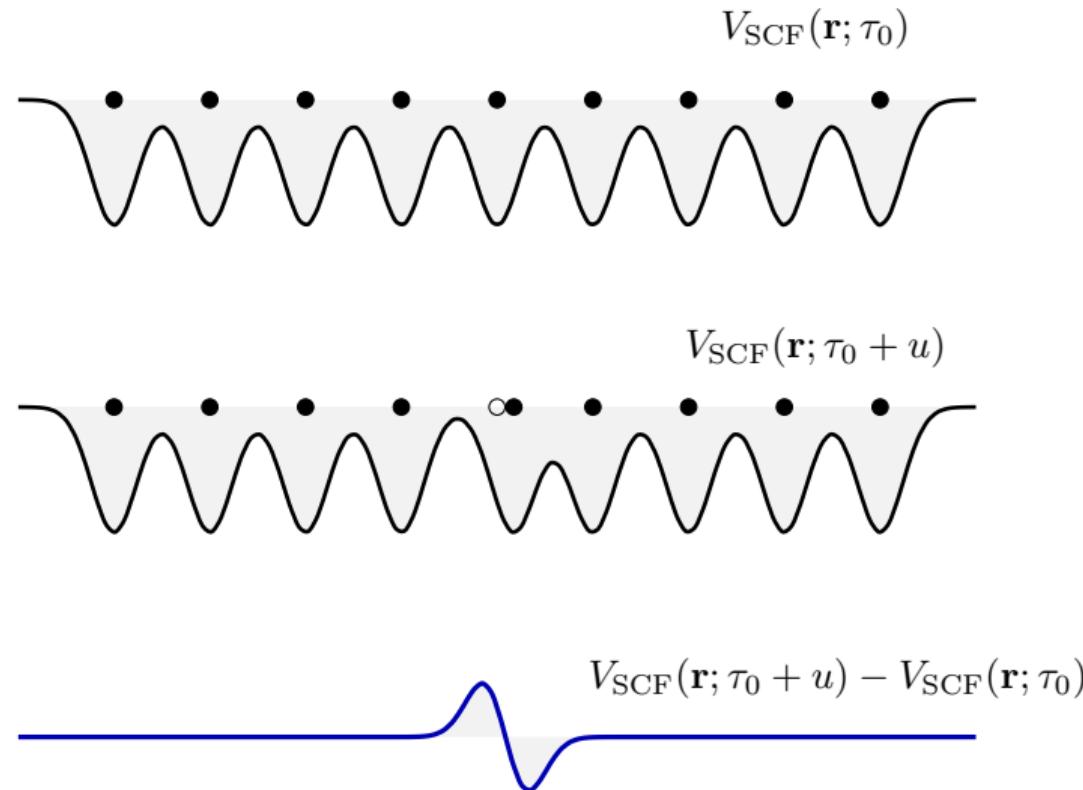
$$V_{\text{SCF}}(\mathbf{r}; \tau_0)$$



$$V_{\text{SCF}}(\mathbf{r}; \tau_0 + u)$$



Perturbation Hamiltonian leading to EPIs



Rayleigh-Schrödinger perturbation theory

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Energy

$$\Delta E_n = \langle n | \frac{\partial V_{\text{SCF}}}{\partial \tau} u | n \rangle$$

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Wavefunction

$$\Delta \psi_n(\mathbf{r}) = \sum_{m \neq n} \frac{\langle m | \frac{\partial V_{\text{SCF}}}{\partial \tau} u | n \rangle}{E_n - E_m} \psi_m(\mathbf{r})$$

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Transition rate

$$\Gamma_{n \rightarrow m} = \frac{2\pi}{\hbar} |\langle m | \frac{\partial V_{\text{SCF}}}{\partial \tau} u | n \rangle|^2 \delta(E_m - E_n - \hbar\omega)$$

Rayleigh-Schrödinger perturbation theory

Energy

$$\Delta E_n = \langle n | \frac{\partial V_{\text{SCF}}}{\partial \tau} u | n \rangle$$

Temperature-dependent band structure

Wavefunction

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Phonon-assisted optical processes and polarons

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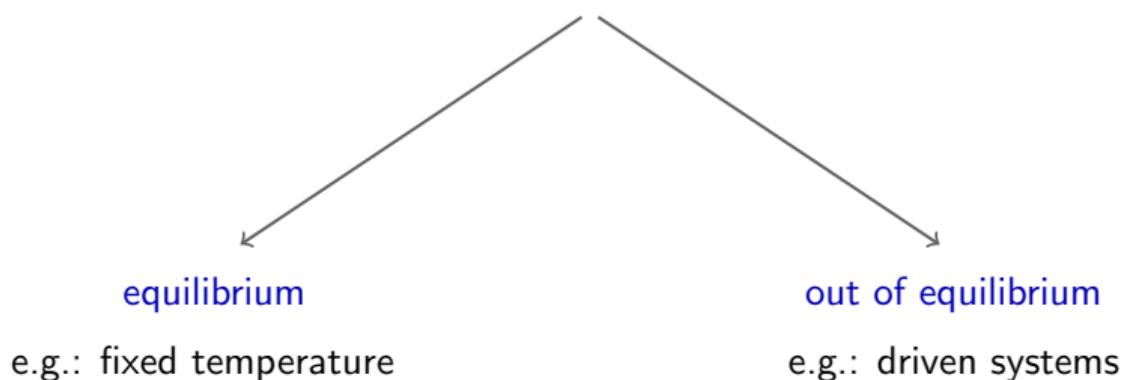
Phonon-limited transport phenomena

Displacement amplitudes

What is the atomic displacement u in the perturbation Hamiltonian?

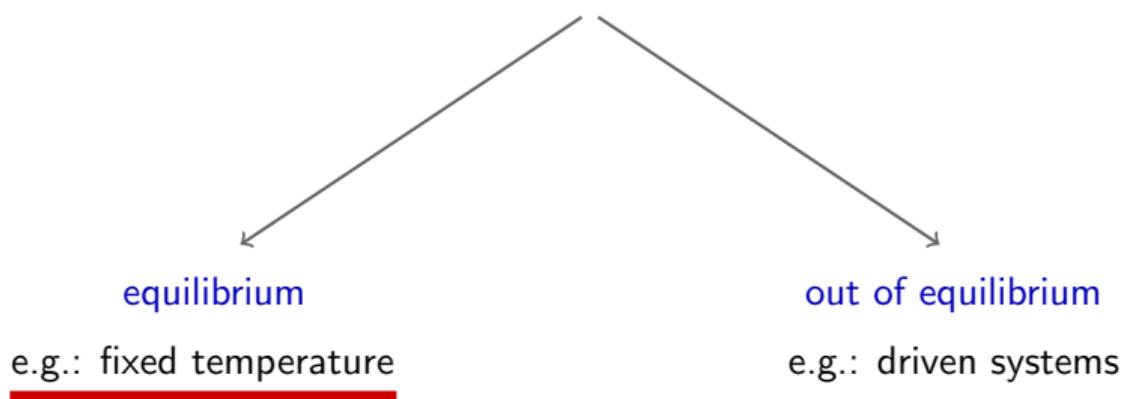
Displacement amplitudes

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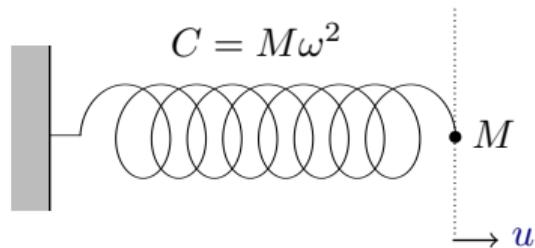
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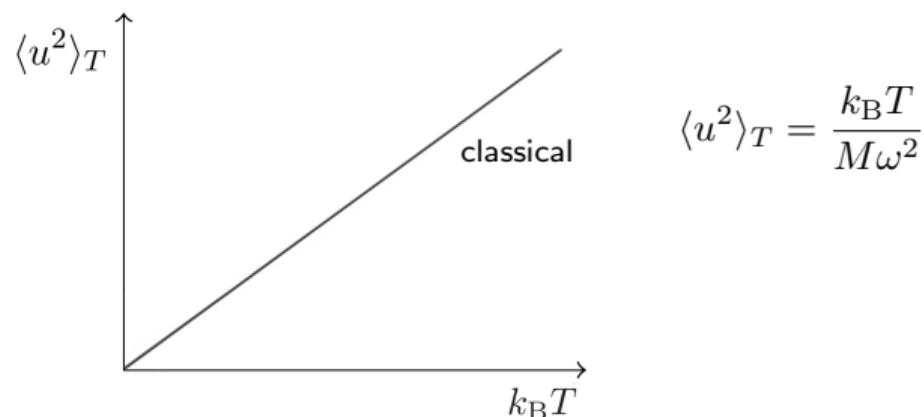
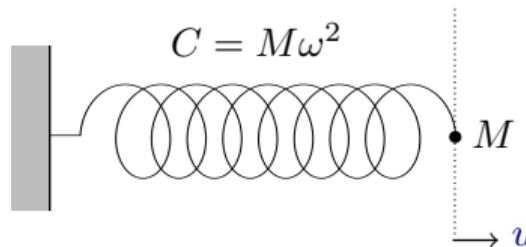


Mean square displacement amplitudes

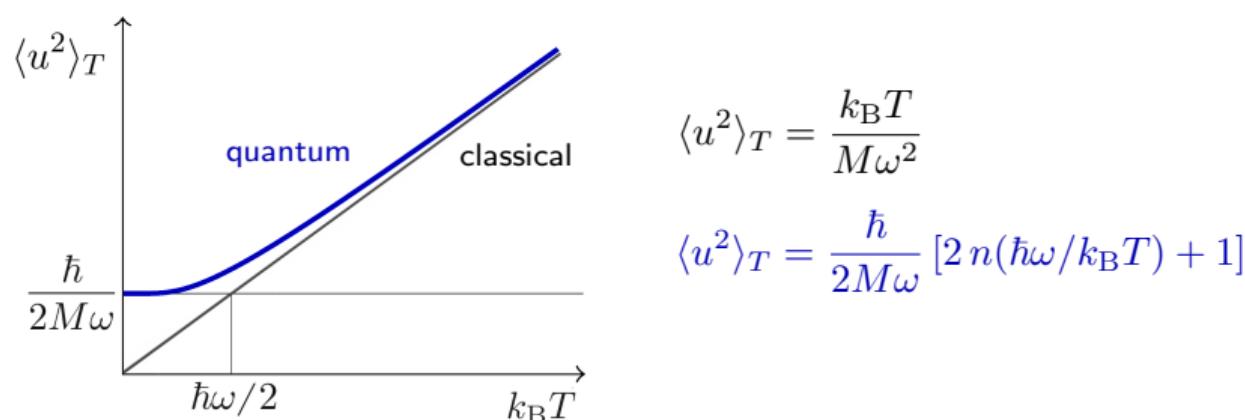
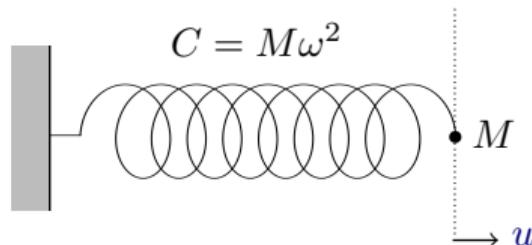
Mean square displacement amplitudes



Mean square displacement amplitudes



Mean square displacement amplitudes



Temperature-dependent band structures

Allen-Heine theory

$$\Delta E_n = \langle n | \frac{\partial V_{\text{SCF}}}{\partial \tau} | n \rangle u$$

Temperature-dependent band structures

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Temperature-dependent band structures

Allen-Heine theory

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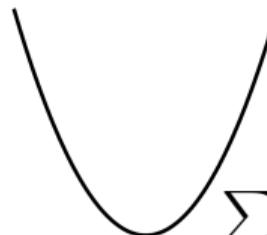
Temperature-dependent band structures

Allen-Heine theory

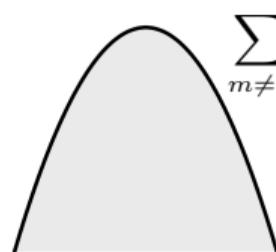
$$\Delta E_n = \cancel{\langle n | \frac{\partial V_{\text{SCF}}}{\partial \tau} | n \rangle} u + \sum_{m \neq n} \frac{\left| \langle m | \frac{\partial V_{\text{SCF}}}{\partial \tau} | n \rangle \right|^2}{E_n - E_m} u^2 + \frac{1}{2} \langle n | \frac{\partial^2 V_{\text{SCF}}}{\partial \tau^2} | n \rangle u^2$$

$$\langle \Delta E_n \rangle_T = \left[\sum_{m \neq n} \frac{\left| \langle m | \frac{\partial V_{\text{SCF}}}{\partial \tau} | n \rangle \right|^2}{E_n - E_m} + \frac{1}{2} \langle n | \frac{\partial^2 V_{\text{SCF}}}{\partial \tau^2} | n \rangle \right] \frac{\hbar}{2M\omega} (2n_T + 1)$$

Temperature-dependent band structures: Basic trends

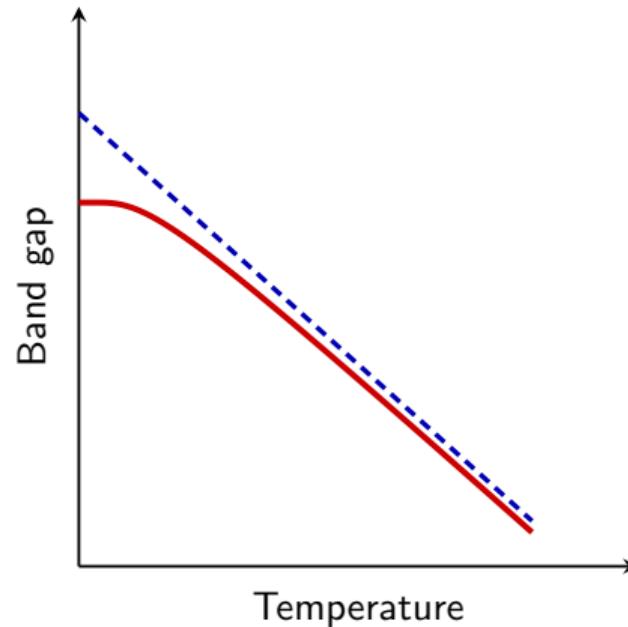
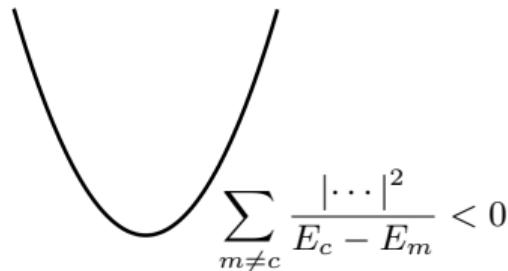


$$\sum_{m \neq c} \frac{|\dots|^2}{E_c - E_m} < 0$$



$$\sum_{m \neq v} \frac{|\dots|^2}{E_v - E_m} > 0$$

Temperature-dependent band structures: Basic trends



Example: Temperature-dependent bands of silicon

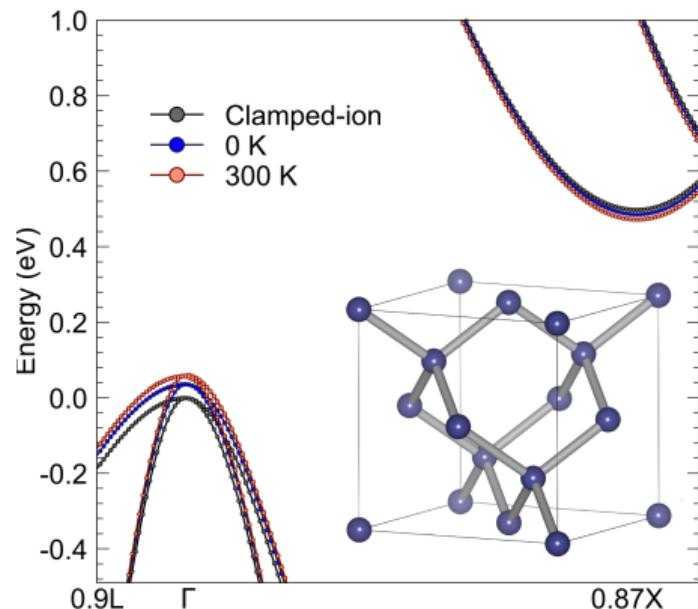


Figure from Zacharias et al, Phys. Rev. Research 2, 013357 (2020)

Example: Temperature-dependent bands of silicon

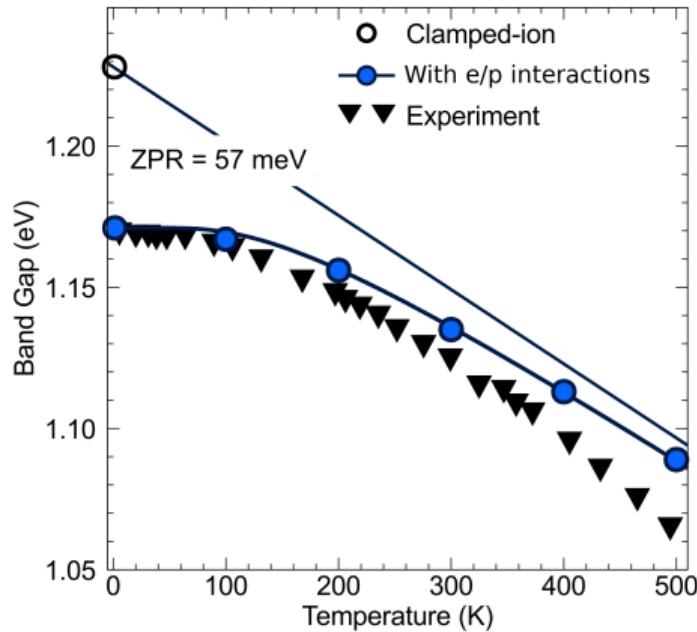
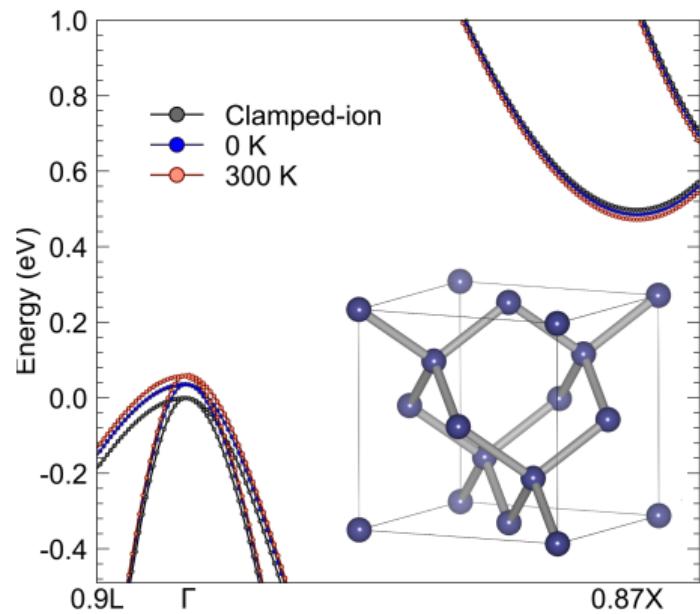


Figure from Zacharias et al, Phys. Rev. Research 2, 013357 (2020)

Phonon-assisted optical absorption

$$\Delta\psi_n(\mathbf{r}) = \sum_{m \neq n} \frac{\langle m | \frac{\partial V_{\text{SCF}}}{\partial \tau} u | n \rangle}{E_n - E_m} \psi_m(\mathbf{r})$$

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$$\epsilon_2(\omega) = \frac{\text{const}}{\omega^2} \sum_{cv} |\langle \textcolor{red}{c} | \hat{p} | \textcolor{red}{v} \rangle|^2 \delta(E_c - E_v - \hbar\omega)$$

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The diagram illustrates the derivation of the dipole operator. A brace groups the term $\langle m | \frac{\partial V_{\text{SCF}}}{\partial \tau} u | n \rangle / (E_n - E_m)$ from the equation above. This brace points down to a bracketed expression: $\langle c + \Delta c |$ on the left, a vertical line in the center, and $|v + \Delta v \rangle$ on the right. Two arrows point downwards from this bracketed expression to the dipole operator term in the equation below.

$$\epsilon_2(\omega) = \frac{\text{const}}{\omega^2} \sum_{cv} |\langle \mathbf{c} | \hat{p} | \mathbf{v} \rangle|^2 \delta(E_c - E_v - \hbar\omega)$$

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$\underbrace{\langle c + \Delta c |}_{cv} \underbrace{|v + \Delta v\rangle}_{cv} \underbrace{\epsilon_2(\omega) = \frac{\text{const}}{\omega^2} \sum_{cv} |\langle c | \hat{p} | v \rangle|^2 \delta(E_c - E_v - \hbar\omega)}_{\left| \sum_{m \neq c} \frac{\langle c | \frac{\partial V_{\text{SCF}}}{\partial \tau} | m \rangle \langle m | \hat{p} | v \rangle}{E_c - E_m} + \dots \right|^2 u^2}$

Phonon-assisted optical absorption

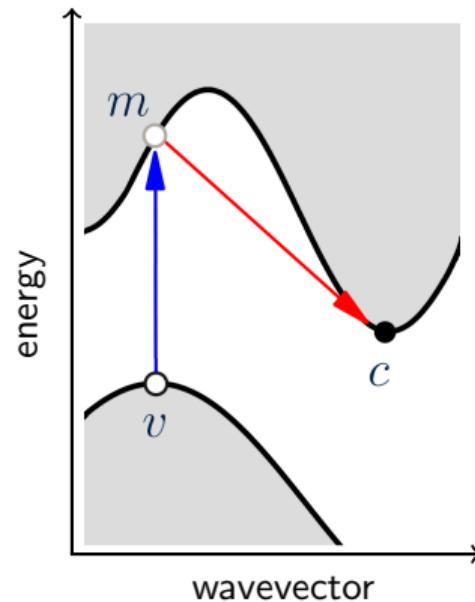
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$\underbrace{\hspace{10em}}$

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Example: Absorption spectrum of silicon

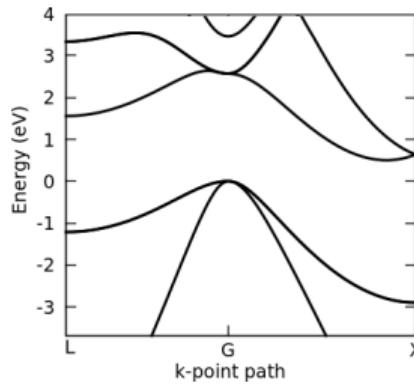
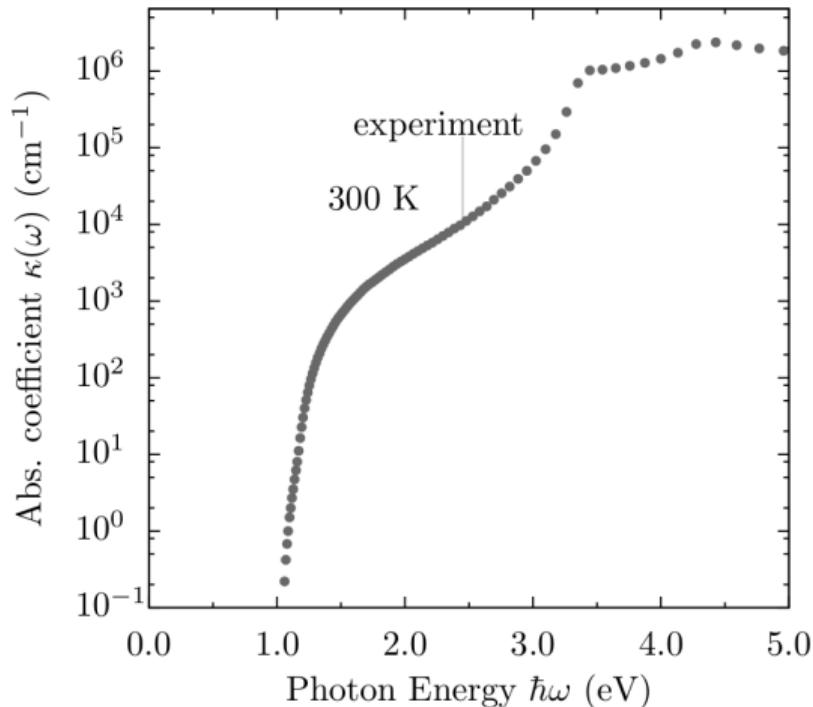


Figure from Zacharias et al, Phys. Rev. Lett. 115, 177401 (2015)
see also: Noffinger et al, Phys. Rev. Lett. 108, 167402 (2012)

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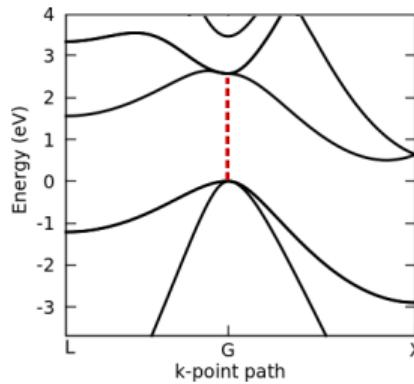
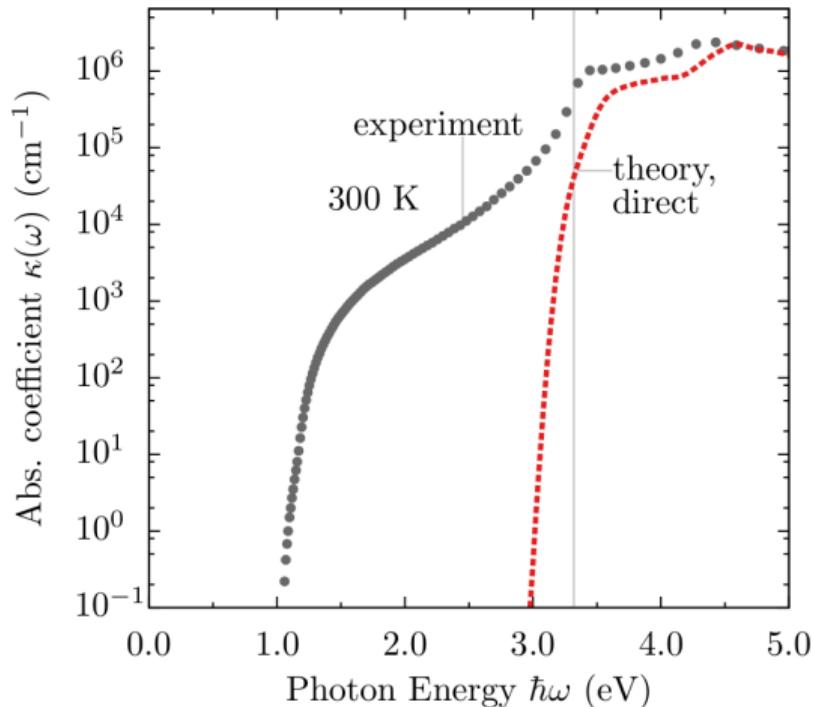


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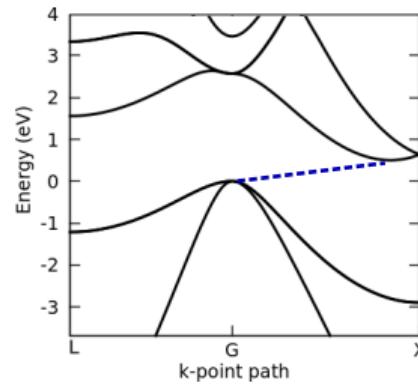
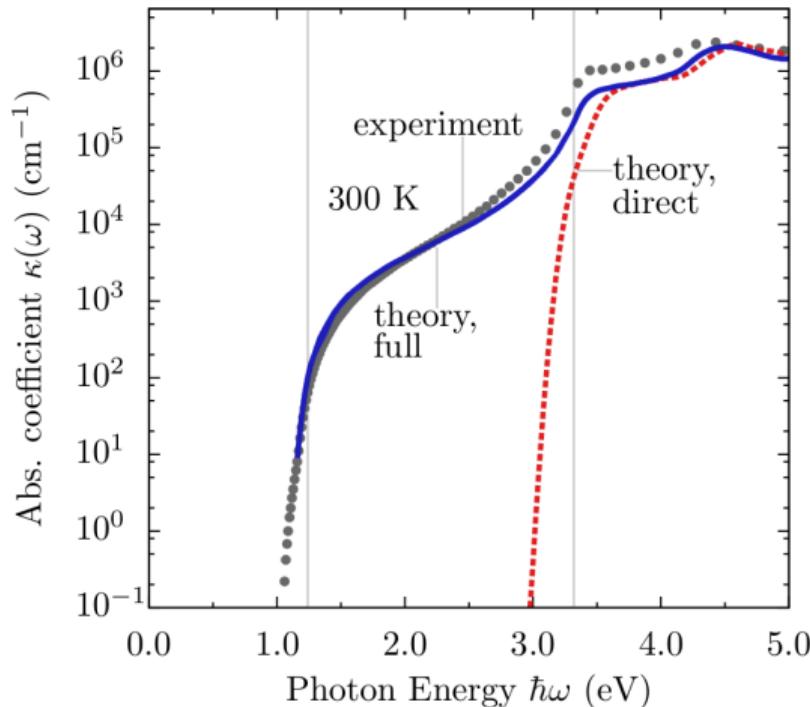


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Phonon-limited carrier mobilities

Carrier relaxation time

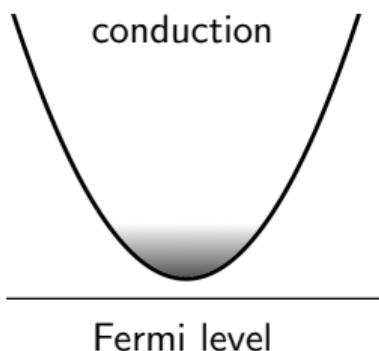
$$\frac{1}{\tau_n} = \sum_m \Gamma_{n \rightarrow m}$$

Phonon-limited carrier mobilities

Carrier relaxation time

$$\frac{1}{\tau_n} = \sum_m \Gamma_{n \rightarrow m}$$

Electron mobility from Boltzmann equation (simplified)



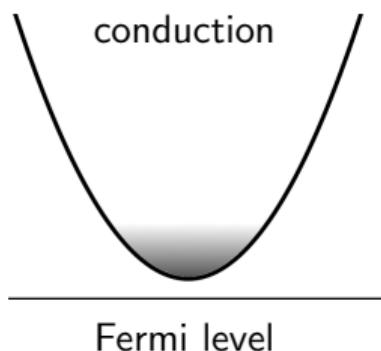
$$\mu_e = \frac{e}{m} \frac{1}{N_c} \sum_{n \in c} \frac{m |\mathbf{v}_n|^2}{3 k_B T} e^{-(E_n - E_F)/k_B T} \tau_n$$

Phonon-limited carrier mobilities

Carrier relaxation time

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Electron mobility from Boltzmann equation (simplified)



$$\mu_e = \underbrace{\frac{e}{m} \frac{1}{N_c} \sum_{n \in c} \frac{m|\mathbf{v}_n|^2}{3k_B T} e^{-(E_n - E_F)/k_B T} \tau_n}_{\downarrow} \quad \mu = \frac{e\langle\tau\rangle}{m} \text{ Drude formula}$$

Example: Mobility of lead-halide perovskite MAPbI_3

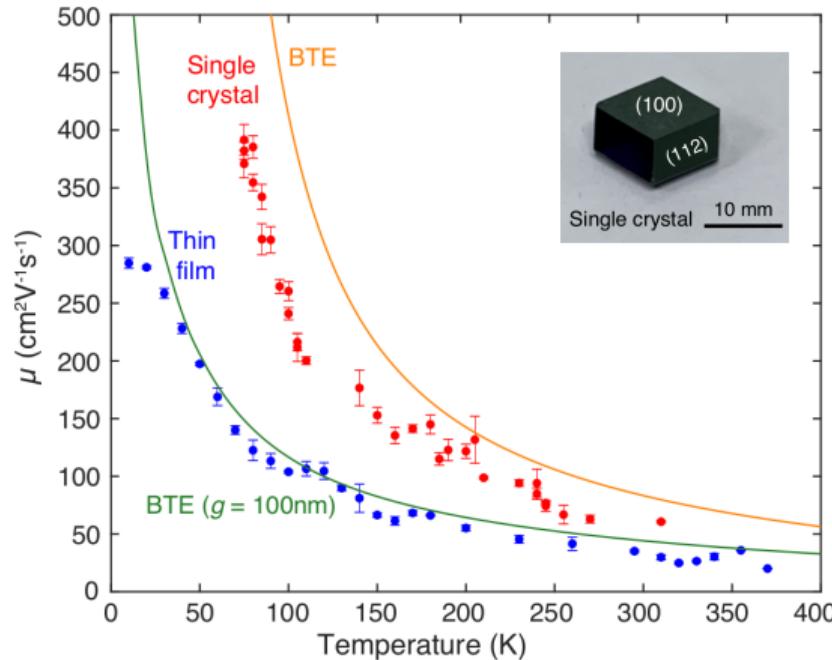


Figure from Xia et al, J. Phys. Chem. Lett. 12, 3607 (2021)

The electron-phonon matrix element

$$\langle \psi_m | \frac{\partial V_{\text{SCF}}}{\partial \tau} | \psi_n \rangle \xrightarrow{\quad} g_{mn\nu}(\mathbf{k}, \mathbf{q}) = \langle u_{m\mathbf{k}+\mathbf{q}} | \Delta_{\mathbf{q}\nu} v_{\text{SCF}} | u_{n\mathbf{k}} \rangle_{\text{uc}}$$

Baroni et al, Rev. Mod. Phys. 73, 515 (2001); Giustino, Rev. Mod. Phys. 89, 015003 (2017)

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↑ ↓
Lattice-periodic part of the wavefunction

Baroni et al, Rev. Mod. Phys. 73, 515 (2001); Giustino, Rev. Mod. Phys. 89, 015003 (2017)

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↑ ↑
Lattice-periodic part of the wavefunction

Lattice-periodic variation
of the self-consistent potential

$$\Delta_{\mathbf{q}\nu} v_{\text{SCF}} = \sum_{\kappa\alpha p} e^{-i\mathbf{q}\cdot(\mathbf{r}-\mathbf{R}_p)} \sqrt{\frac{\hbar}{2M_\kappa \omega_{\mathbf{q}\nu}}} e_{\kappa\alpha,\nu}(\mathbf{q}) \frac{\partial V_{\text{SCF}}(\mathbf{r})}{\partial \tau_{\kappa\alpha p}}$$

Baroni et al, Rev. Mod. Phys. 73, 515 (2001); Giustino, Rev. Mod. Phys. 89, 015003 (2017)

The electron-phonon matrix element

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Lattice-periodic part of the wavefunction

Lattice-periodic variation
of the self-consistent potential

Potential change
from ionic displacement

$$\Delta_{\mathbf{q}\nu} v_{\text{SCF}} = \sum_{\kappa\alpha p} e^{-i\mathbf{q}\cdot(\mathbf{r}-\mathbf{R}_p)} \sqrt{\frac{\hbar}{2M_\kappa \omega_{\mathbf{q}\nu}}} e_{\kappa\alpha,\nu}(\mathbf{q}) \frac{\partial V_{\text{SCF}}(\mathbf{r})}{\partial \tau_{\kappa\alpha p}}$$

Baroni et al, Rev. Mod. Phys. 73, 515 (2001); Giustino, Rev. Mod. Phys. 89, 015003 (2017)

The electron-phonon matrix element

$$\langle \psi_m | \frac{\partial V_{\text{SCF}}}{\partial \tau} | \psi_n \rangle \longrightarrow g_{mn\nu}(\mathbf{k}, \mathbf{q}) = \langle u_{m\mathbf{k}+\mathbf{q}} | \Delta_{\mathbf{q}\nu} v_{\text{SCF}} | u_{n\mathbf{k}} \rangle_{\text{uc}}$$

Lattice-periodic part of the wavefunction

Lattice-periodic variation
of the self-consistent potential

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Phonon
polarization

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Incommensurate
modulation

Zero-point
amplitude

Potential change
from ionic displacement

Phonon
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Baroni et al, Rev. Mod. Phys. 73, 515 (2001); Giustino, Rev. Mod. Phys. 89, 015003 (2017)

Brillouin Zone integrals

Example: electron lifetimes in metals (adiabatic, high temperature)

$$\frac{1}{\tau_{n\mathbf{k}}} = 2k_B T \frac{2\pi}{\hbar} \sum_{m\nu} \int_{\text{BZ}} \frac{d\mathbf{q}}{\Omega_{\text{BZ}}} \frac{|g_{nm\nu}(\mathbf{k}, \mathbf{q})|^2}{\hbar\omega_{\mathbf{q}\nu}} \delta(\varepsilon_{n\mathbf{k}} - \varepsilon_{m\mathbf{k}+\mathbf{q}})$$



Fermi surface of copper

Brillouin Zone integrals

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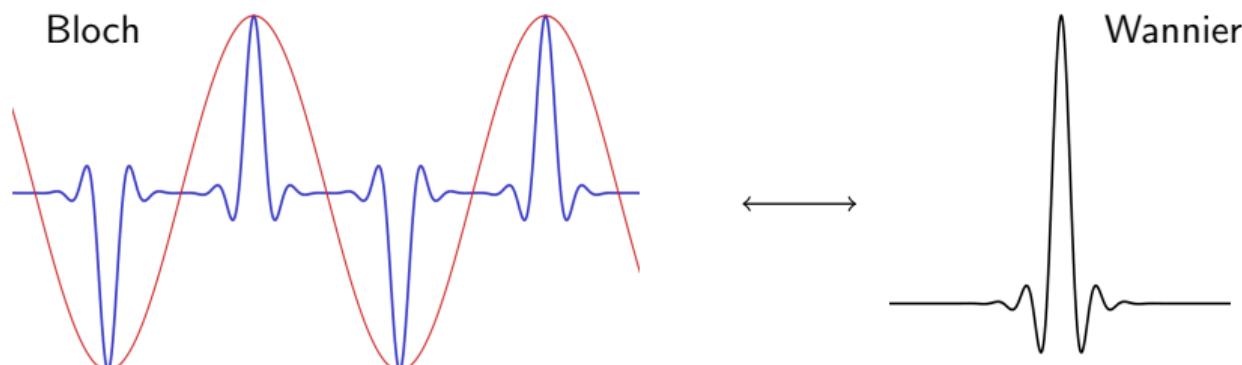
Fermi surface of copper

- The integral over the Brillouin zone can require grids with $100 \times 100 \times 100$ q-points and more: **expensive**
- Each q-vector requires a separate DFPT calculation: **expensive**

Wannier interpolation of electron-phonon matrix elements

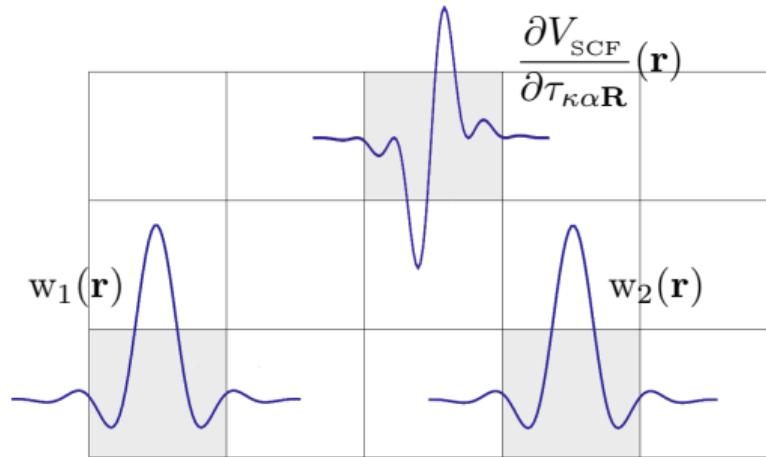
Wannier functions

$$w_{mp}(\mathbf{r}) = \frac{1}{N_p} \sum_{n\mathbf{k}} e^{-i\mathbf{k}\cdot\mathbf{R}_p} U_{nm\mathbf{k}} \psi_{n\mathbf{k}}(\mathbf{r})$$



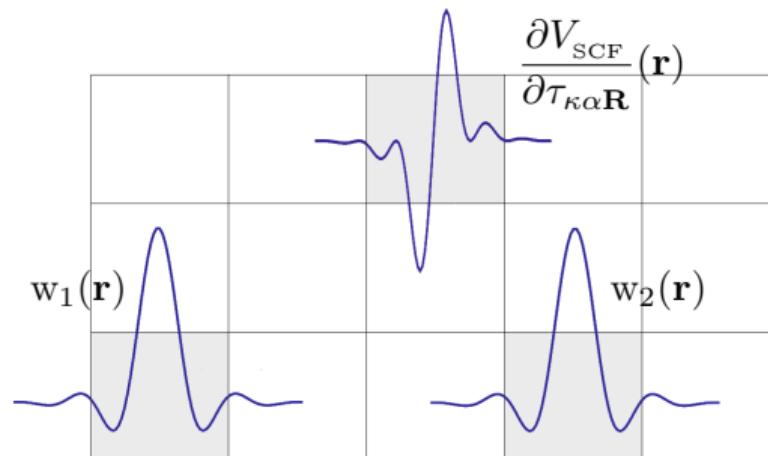
Marzari et al, Rev. Mod. Phys. 84, 1419 (2012)

Wannier interpolation of electron-phonon matrix elements



FG, Rev. Mod. Phys. 89, 015003 (2017)

Wannier interpolation of electron-phonon matrix elements



$$\mathbf{g}_\nu(\mathbf{k}, \mathbf{q}) = \sqrt{\frac{\hbar}{2M_\kappa \omega_{\mathbf{q}\nu}}} \sum_{\mathbf{R}\mathbf{R}'} e^{i(\mathbf{k}\cdot\mathbf{R} + \mathbf{q}\cdot\mathbf{R}')} U_{\mathbf{k}+\mathbf{q}} \mathbf{g}(\mathbf{R}, \mathbf{R}') \cdot \mathbf{e}_{\mathbf{q}\nu} U_{\mathbf{k}}^\dagger$$

FG, Rev. Mod. Phys. 89, 015003 (2017)

Example: Electron-phonon matrix elements of diamond

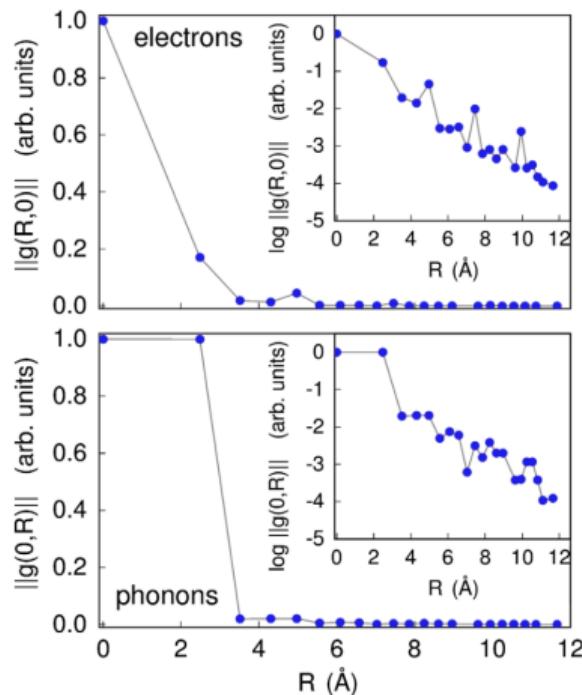


Figure from FG et al, Phys. Rev. B 76, 165108 (2007)

Example: Electron-phonon matrix elements of diamond

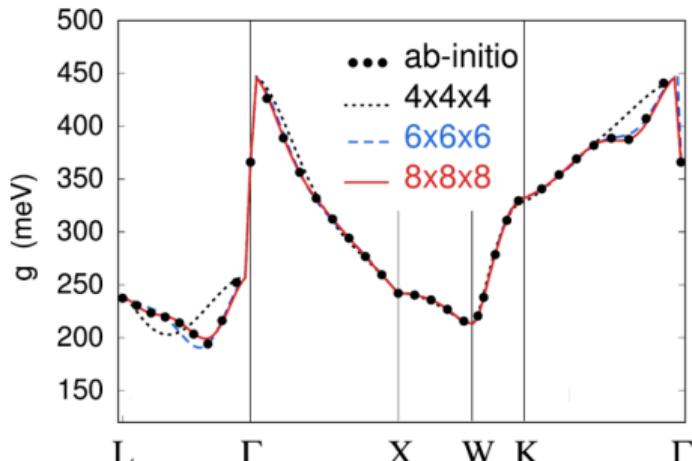
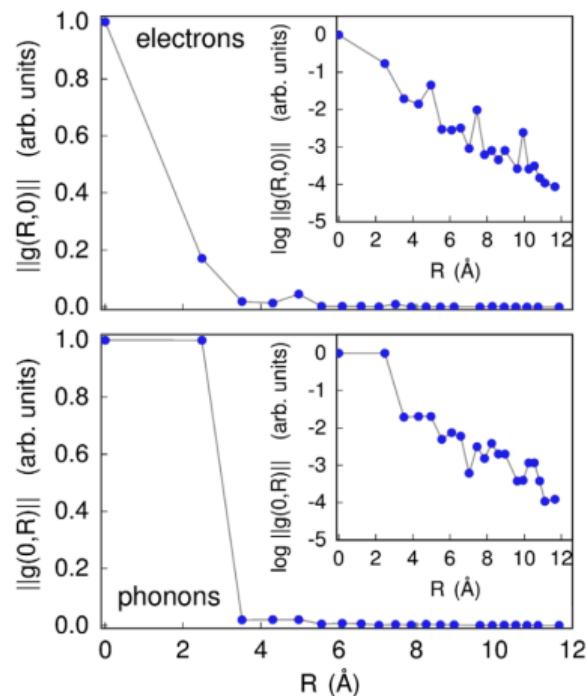
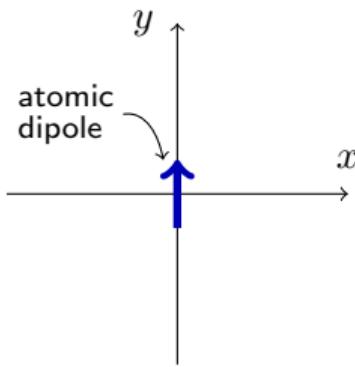
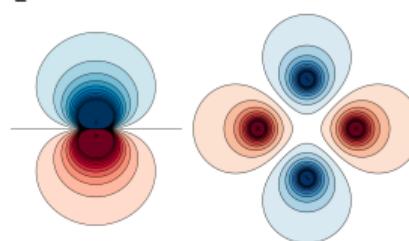


Figure from FG et al, Phys. Rev. B 76, 165108 (2007)

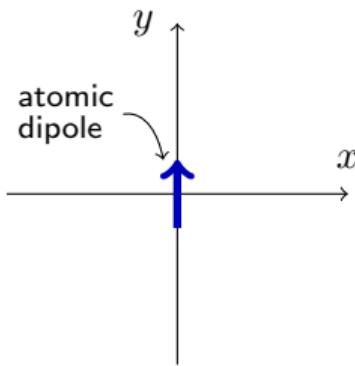
Spatial decay of induced potential



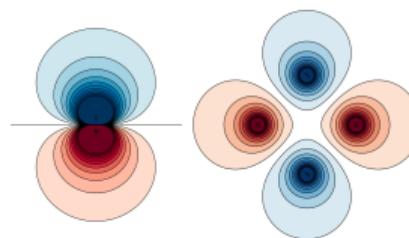
$$\frac{\partial V_{\text{SCF}}}{\partial \tau}(\mathbf{r}) \sim \epsilon^{-1} \left[D_\alpha \frac{\hat{r}_\alpha}{r^2} + Q_{\alpha\beta} \frac{\hat{r}_\alpha \hat{r}_\beta}{r^3} + O_{\alpha\beta\gamma} \frac{\hat{r}_\alpha \hat{r}_\beta \hat{r}_\gamma}{r^4} + \dots \right]$$



Spatial decay of induced potential



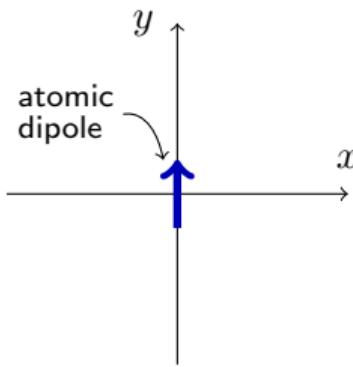
$$\frac{\partial V_{\text{SCF}}}{\partial \tau}(\mathbf{r}) \sim \epsilon^{-1} \left[D_\alpha \frac{\hat{r}_\alpha}{r^2} + Q_{\alpha\beta} \frac{\hat{r}_\alpha \hat{r}_\beta}{r^3} + O_{\alpha\beta\gamma} \frac{\hat{r}_\alpha \hat{r}_\beta \hat{r}_\gamma}{r^4} + \dots \right]$$



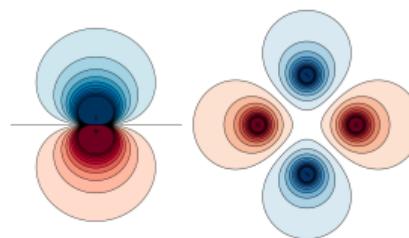
Fourier:

$\frac{1}{q}$	1	q
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Spatial decay of induced potential



$$\frac{\partial V_{\text{SCF}}}{\partial \tau}(\mathbf{r}) \sim \epsilon^{-1} \left[D_\alpha \frac{\hat{r}_\alpha}{r^2} + Q_{\alpha\beta} \frac{\hat{r}_\alpha \hat{r}_\beta}{r^3} + O_{\alpha\beta\gamma} \frac{\hat{r}_\alpha \hat{r}_\beta \hat{r}_\gamma}{r^4} + \dots \right]$$



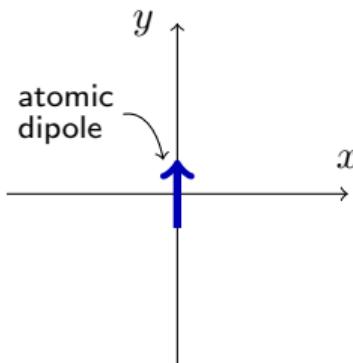
Fourier:

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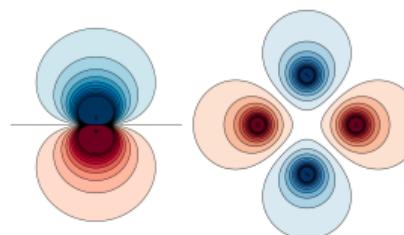
Metals: $\epsilon(q) = 1 + \frac{q_{\text{TF}}^2}{q^2}$

Insulator: $\epsilon(q) = 1 + \frac{\epsilon_0 - 1}{1 + q^2/q_0^2}$

Spatial decay of induced potential



$$\frac{\partial V_{\text{SCF}}}{\partial \tau}(\mathbf{r}) \sim \epsilon^{-1} \left[D_\alpha \frac{\hat{r}_\alpha}{r^2} + Q_{\alpha\beta} \frac{\hat{r}_\alpha \hat{r}_\beta}{r^3} + O_{\alpha\beta\gamma} \frac{\hat{r}_\alpha \hat{r}_\beta \hat{r}_\gamma}{r^4} + \dots \right]$$



Fourier:

$$\frac{1}{q} \quad 1 \quad q$$

Metals: $\epsilon(q) = 1 + \frac{q_{\text{TF}}^2}{q^2}$ smooth smooth smooth

Insulator: $\epsilon(q) = 1 + \frac{\epsilon_0 - 1}{1 + q^2/q_0^2}$ singular discontinuous smooth

Example: Fröhlich interaction matrix element in TiO_2

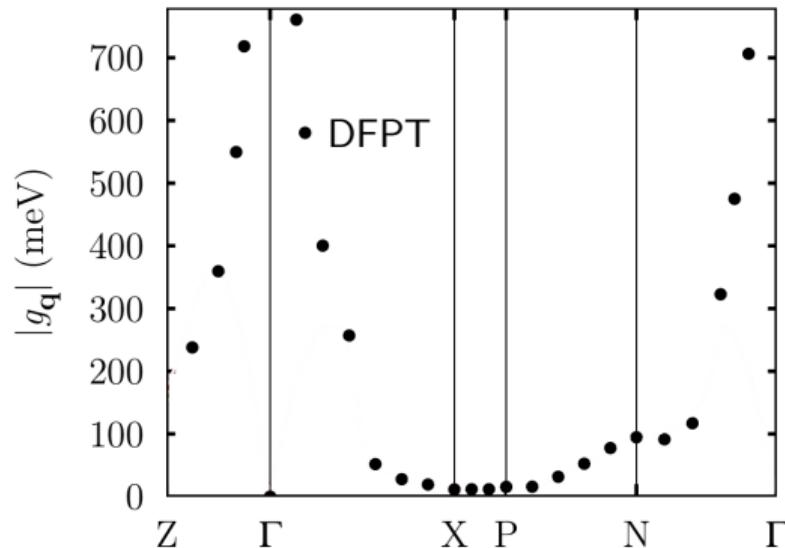
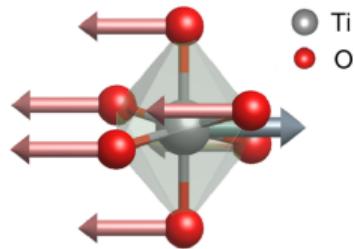


Figure from Verdi et al, Phys. Rev. Lett. 115, 176401 (2015)

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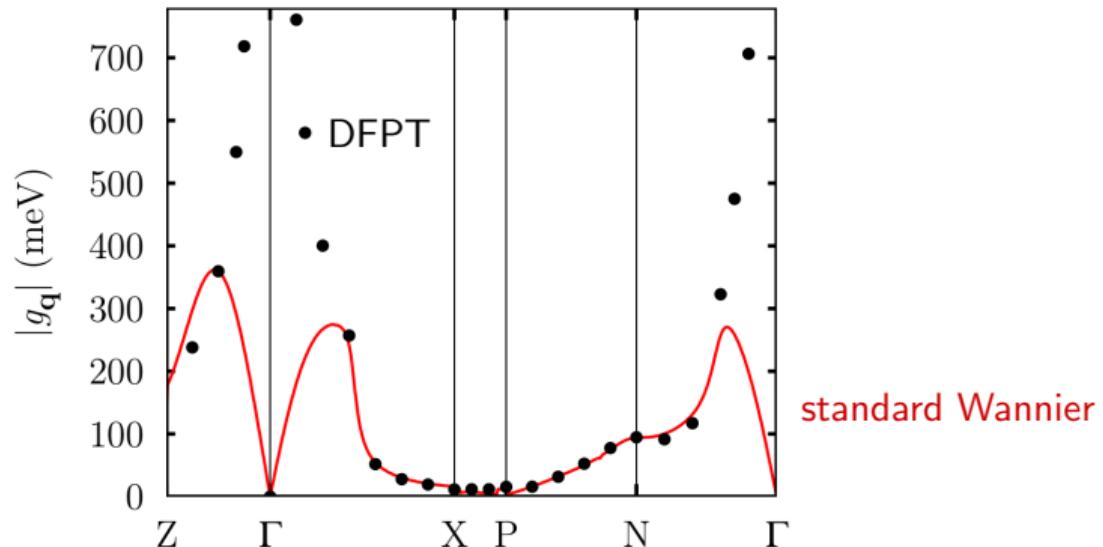
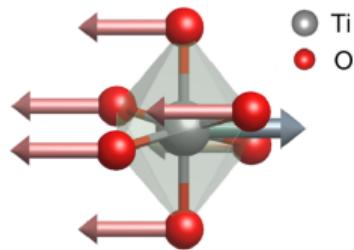


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Example: Fröhlich interaction matrix element in TiO_2

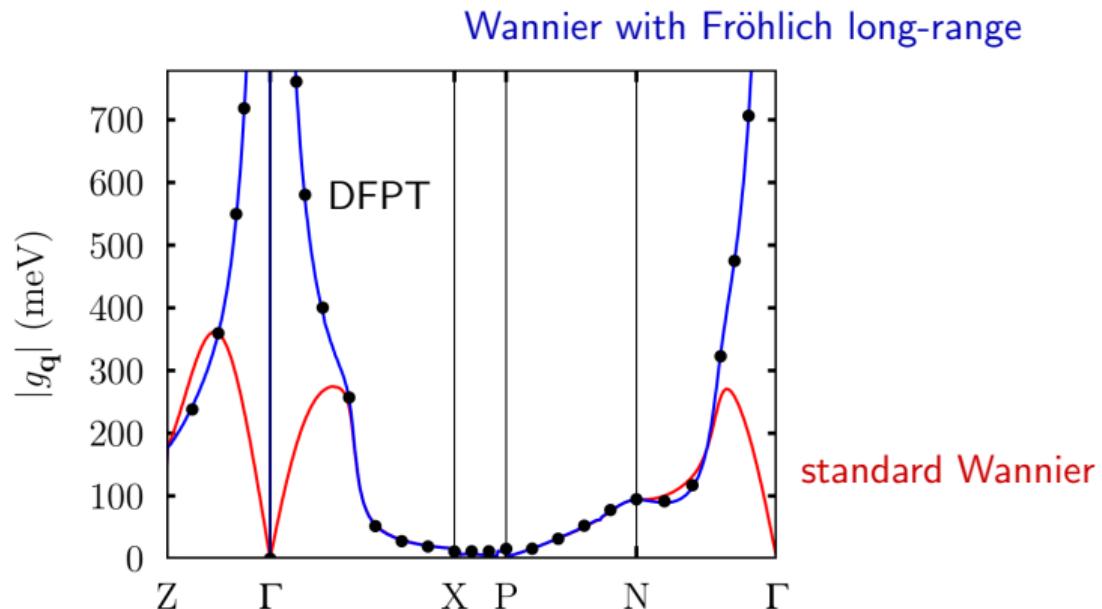
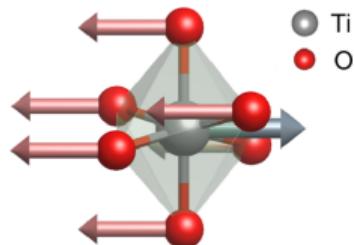


Figure from Verdi et al, Phys. Rev. Lett. 115, 176401 (2015)

Take-home messages

- We can understand the basics of electron-phonon physics using elementary perturbation theory
- Calculations of EPIs require a fine sampling of the electron-phonon matrix elements across the Brillouin zone
- The EPI matrix elements of metals and insulators behave very differently for long-wavelength phonons

References

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- Giustino, Rev. Mod. Phys. 89, 015003 (2017) [\[link\]](#)
- Baroni et al, Rev. Mod. Phys. 73, 515 (2001) [\[link\]](#)
- Marzari et al, Rev. Mod. Phys. 84, 1419 (2012) [\[link\]](#)
- Verdi et al, Phys. Rev. Lett. 115, 176401 (2015) [\[link\]](#)
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- Jhalani et al, Phys. Rev. Lett. 125, 136602 (2020) [\[link\]](#)